Overview
MOSFETS are voltage-controlled switches. Unlike triacs, MOSFETS have the capability of being turned on and turned off. They also switch much faster than triacs. As illustrated in Figure 1, the MOSFET acts as a unidirectional switch between the drain and source terminals, and has an internal antiparallel diode. An applied gate-to-source voltage of approximately 4 or 5 V is sufficient to turn on the MOSFET (i.e., resistance between drain and source becomes a few tenths of an ohm). Faster turn on is achieved when 12-18 V is applied. Then, when the gate-to-source voltage is set to zero, the MOSFET turns off (i.e., drain-to-source resistance becomes very large).

A Warning about Static Electricity
Until they are properly mounted with a gate pull-down resistor, a MOSFET is very sensitive to burn out if its gate terminal is touched. Do not take the MOSFET out of its anti-static bag until you are ready to mount it on the PC board, and then always use a grounded static wrist strap and/or static mat when handling the MOSFET. Avoid touching the gate terminal.

When using a wrist strap, attach the wrist alligator clip end of the strap to the metal switch plate cover on the right-hand side of the lab benches. As an extra precaution, frequently touch the metal power switch plate cover with your hand.

Testing a MOSFET
If you suspect that your MOSFET has failed, perform the following test:
- Remove any connections to either the drain or source terminals, except keep the 100kΩ pull-down resistor connected from gate to source.
- With no V_{GS} applied, measure R_{DS} with an ohmmeter. Expect R_{DS}\rightarrow\infty (i.e., M\Omega s).
- Now, while measuring R_{DS}, temporarily connect a 6-to-18V V_{GS}. Expect to see R_{DS}\rightarrow0 (i.e., few tenths \Omega). Remove the temporary connection, and expect to return to R_{DS}\rightarrow\infty.

This test can be also be performed with the MOSFET tester in the power lab. The tester circuit is mounted on a piece of wood and uses a 1” diameter red LED for testing under load.
The Firing Circuit
The MOSFET firing circuit used in this experiment, shown in Figure 2, contains two IC chips (i.e., a pulse-width modulator, and a MOSFET inverting driver). The pulse width modulator compares a sawtooth wave to a 0-5V\textsubscript{dc} reference voltage to produce a 5V rectangular-wave logic output with controllable duty cycle D. As the reference voltage increases, D decreases (thus, an inverted response). This output serves as the input to the inverting MOSFET driver that, in turn, provides the voltage and current to quickly switch the MOSFET.

Figure 2. MOSFET Firing Circuit (ordered through Express PCB.com)
The voltage divider for duty cycle control consists of two resistors and either an A10kΩ (for Buck) or B10kΩ (for Boost or Buck/Boost) potentiometer. The “A” in “A10kΩ” stands for audio taper, meaning that the resistance of the potentiometer varies logarithmically. B10kΩ has linear taper. In Figure 2, as the duty cycle “D” potentiometer is turned clockwise, voltage to the “Duty” pin #1 increases, the duty cycle of the pulses to the inverting driver chip decreases, so that D of the inverting driver output increases. The combination of resistors and potentiometer prevent D from exceeding 0.95 for buck, and 0.80 and 0.70 for boost and buck/boost, so that the MOSFET is never fully “on” (an important feature for boost or buck/boost converters). The modeled variations are given in Figures 3a, 3b, and 3c.

The sawtooth wave frequency of the PWM modulator is proportional to 1/RC, where R is the series combination of an A10kΩ potentiometer and 470Ω resistor, and C is 6.8nF. Decreasing R increases frequency. In Figure 2, turning the A10kΩ “Freq” potentiometer clockwise decreases R, and thus increases frequency. As the potentiometer is turned clockwise, the amount of resistance change per angular degree of movement decreases. The nonlinear resistance variation of an audio pot yields a more linear variation of frequency than can be achieved with a linear potentiometer (see Figure 4).

![D vs. Potentiometer Angle](image)

Figure 3a. Duty Cycle D (and Vout/Vin) Variation in Buck Converter vs. Potentiometer Angle (EE362L_MOSFET_Firing_Circuit_Duty_Variation.xls)
Figure 3b. Vout/Vin Variation in Boost Converter vs. Potentiometer Angle
(EE362L_MOSFET_Firing_Circuit_Duty_Variation.xls)

Figure 3c. Vout/Vin Variation in Buck/Boost Converter vs. Potentiometer Angle
(EE362L_MOSFET_Firing_Circuit_Duty_Variation.xls)
Circuit Construction:

- Ohm-check the PC board **before** mounting any components. This means ohm-checking each pad for connections to the ground plane, power plane, or neither plane.

- Traces are rated per 0.025” of width. Thus, a 0.10” trace is rated 4A. The widest single trace available is 0.15”, corresponding to 6A. Traces can be paralleled.

- It is best to keep at least 0.2” between components

- Personal preference – no traces on the bottom side

- Use nylon screws and standoffs to support the PC board

- Wide traces are stronger, especially at corners, and easy to touch with a scope probe

- Personal preference – use ½ W resistors because it is easy to attach a scope probe to their leads

- Resistor bodies should be slightly elevated so they do not touch the PC board

- Use sockets for the chips so they can be easily replaced and removed for reuse.
Next: Temporarily connect a 12V\textsubscript{dc} regulated wall wart to the DC jack and use a voltmeter to determine which pin is +12V, and which pin is ground. Now, disconnect the wall wart. Then,

1. Mount and solder the 100k\Omega MOSFET gate-to-source pull-down resistor.

2. Mount and solder the three-terminal Phoenix Contact “green plug,” so that the tightening screws face the outer edge of the PC board.

3. Mount the 1.5” corner bracket with two #6 nylon knurled-head thumb screws, using a ¼” #6 nylon spacer between each screw and the surface of the PC board.

4. **The most important step.** Use a static wristband. Avoid touching the gate terminal. Take the MOSFET out of the pink antistatic bag, place a very thin layer of heat sink compound on the back of the MOSFET, and run a #4 nylon knurled-head thumb screw through the MOSFET and heat sink holes. Insert the MOSFET pins into the green plug and push the #4 thumb screw through the 1.5” bracket. Place a 1/8\textsuperscript{th} inch, #6 nylon spacer on the back of the corner bracket, and tighten the assembly with a #4, ¾ inch threaded spacer. Then, tighten the green plug’s three screws to make a solid electrical connection with the MOSFET’s pins.

Figure 5. MOSFET Assembly
5. Mount the DC jack. Before soldering any leads to the jack, plug in a 12Vdc wall to
determine the + and – terminals. Then, disconnect the 12Vdc wall wart.

6. Mount all remaining components.

7. Plug in the wall wart. Make sure that each chip is receiving the proper +12V supply
voltage. Do this using multimeter measurements directly at the appropriate pins on the
chips. Check the voltage at pin 12 of the PWM modulator chip with respect to ground.
Expect 5V.

8. Connect an oscilloscope probe to the logic output of the PWM chip (i.e., pin 8). Adjust
D. The waveform should vary sharply between zero and (about) 4.5V, with inverted duty
cycle. Move the probe to the output of the driver to view $V_{GS}$. This $V_{GS}$ is “open
circuit” because the driver is not yet connected to the MOSFET. The waveform should
be switching sharply between 0 and 12V. Use the oscilloscope to measure duty cycle D
and frequency F. Vary the D and F potentiometers to observe the ranges of D and F.
Expect $0.05 < D < 0.95$ (for buck), and $15\text{kHz} < F < 200\text{kHz}$. D and F should increase as
their respective potentiometers are rotated clockwise. Save a representative screen
snapshot of $V_{GS}$ for your report, with $D \approx 0.8$, and $F \approx 150\text{kHz}$.

9. Lower D to the minimum, and unplug the wall wart.
PWM Logic Output (i.e., Pin 8)

Open-Circuited Driver Chip Output $V_{GS}$
10. Screw a 0.022µF ceramic capacitor to the MOSFET drain and source green plug terminals.

11. Use #14 or #16 wire jumpers to connect a DBR and three headlights, forming a series circuit as shown in Figure 6. Keep the wires as short as possible.

![Figure 6. MOSFET Light Dimmer Circuit](image)

(Note – the ground of the wall wart and protoboard is a different potential than the ground of the DBR. Do not connect these grounds together.)

12. Make sure that the DBR switch is “off.” Plug the DBR into a 25V transformer, and the 25V transformer into a variac. Set the variac voltage to zero.

13. Plug in the wall wart, turn “on” the DBR switch, and slowly raise the variac output to 120V.

14. Now, use the MOSFET as a DC light dimmer. Observe \( V_{GS} \) at the MOSFET on an oscilloscope while varying \( D \) and \( F \) over their ranges. Save the \( V_{GS} \) waveform with \( D \approx 0.8 \), and \( F \approx 150\text{kHz} \).
15. Observe $V_{DS}$ at the MOSFET on an oscilloscope while varying $D$ and $F$ over their ranges. Save the $V_{DS}$ waveform with $F \approx 150\, \text{kHz}$, $D \approx 0.8$. Measure the peak value of $V_{DS}$, and use cursors to estimate the turn-off and turn-on ringing frequencies.

$V_{GS}$ with Three Series Headlight Load

$V_{DS}$ with Three Series Headlight Load, with Snubber Capacitor, showing a Peak Value of About 45V

[note – the duty cycle of $V_{DS}$ is $(1 - D)$]
$V_{DS}$ **Turn-Off** Transient, with Snubber Capacitor, is approximately 633kHz

$V_{DS}$ **Turn-On** Transient, with Snubber Capacitor, is approximately 3.9MHz
16. **Turn off the DBR**, and then remove the snubber capacitor. Power up, and repeat the peak voltage and turn-off frequency measurements. Observe the impact that the snubber capacitor has on the peak value of $V_{DS}$. **Note – do not remove or connect the snubber with DBR power applied because the resulting sparks can burn out the MOSFET.**

![Image of VDS with Three Series Headlight Load, without Snubber Capacitor, showing a Peak Value of about 167V](image)

**$V_{DS}$ with Three Series Headlight Load, without Snubber Capacitor, showing a Peak Value of about 167V**

![Image of VDS Turn-Off Transient, without Snubber Capacitor, is approximately 3.8MHz](image)

**$V_{DS}$ Turn-Off Transient, without Snubber Capacitor, is approximately 3.8MHz**

(note – while the turn-on transient is not shown, is about the same as the “with snubber” case because the snubber capacitor is essentially shorted when the MOSFET is turning on)
Optional Calculation
Given that the snubber capacitor is 0.022μF, and that the turn-off is a highly underdamped second-order response, can you use the two measured turn-off frequencies to determine the equivalent parallel L and C of the system components and wiring? Note – the C is mostly the MOSFET off-state drain-to-source capacitance, and the L is mostly the wiring inductance.

Parts List
- MOSFET (N-channel, TO-3P case style). **Careful - static sensitive.** 250V, 22A, Fairchild FQAF34N25 (Mouser #512-FQAF34N25) or 40A, FQA40N25 (Mouser #512-FQA40N25)
- Heat sink, Aavid Thermalloy, 1.65” x 1.00” x 2.00”, 4.5°C/W, (Mouser # 532-529901B02500),
- One 1.5” steel corner bracket
- One 1” steel corner bracket, with a hole drilled out to 5/16” (to accommodate the DC jack)
- DC jack, panel mount, 2.1mm for 12Vdc regulated wall wart (DGS split pin, Mouser #163-4304)
- Two A10kΩ, 9mm, vertical, snap-in potentiometers with audio taper (Mouser #317-2080F-10K)
- One B10kΩ, 9mm, vertical, snap-in potentiometers with linear taper (Mouser #317-2090F-10K)
- PWM modulator chip (ON Semiconductor MC34060A, Newark #24K4038 or Mouser #863-MC34060APG)
- 14-pin DIP socket for above chip (Mill-Max open body, Mouser #575-199314)
- MOSFET inverting driver chip (MICROCHIP TC1426CPA, Mouser #579-TC1426CPA)
- 8-pin DIP socket for above chip (Mill-Max open body, Mouser #575-199308)
- One 6.8nF, 50V ceramic disk capacitor (Mouser #140-50P5-682K-RC) (in student parts bin)
- One 0.01μF, 100V ceramic disk capacitor (Mouser #140-100Z5-103Z-RC) (in student parts bin)
- One 0.022μF, 100V ceramic disk capacitor (Mouser #140-100Z5-223Z-RC) (in student parts bin)
- One 1μF, 50V, high frequency capacitor
- 10Ω, ½W resistor (in student parts bin)
- 680Ω, ½W resistor (in student parts bin)
- 1.5kΩ, ½W resistor (in student parts bin)
- Two 2.2kΩ, ½W resistors (in student parts bin)
- 4.7kΩ, ½W resistor (in student parts bin)
- Two 100kΩ, ½W resistor (in student parts bin)

Nylon hardware for PC Board version, Fall 09
- One #4-40 knurled-head thumb screw, ¾ inch, Mouser #561-T0440075 (holds MOSFET to 1.5” steel corner bracket and heat sink).
- One #4-40 threaded nylon spacer, ¾ inch, Mouser #561-TSP4 (holds MOSFET), with #6 flat washer, Mouser #561-D6125, between it and the corner bracket.
- Three #6-32 knurled-head thumb screws, ¼ inch, Mouser #561-T0632075 (two hold 1.5” steel corner bracket to PC board, and one holds 1” steel corner bracket to PC board).
• Three #6 flat washers, 1/4 inch thick, Mouser #561-D6250 (separates the brackets from the PC board).
• Three #6-32 hex nuts, Mouser #561-G632 (on underside of PC board for the brackets).
• Four #8-32 knurled-head thumb screws, ¾ inch, Mouser #561-T0832075 (one to support each corner), and four #8-32 threaded nylon spacers, ¾ inch, Mouser #561-TSP14.

Plastic bags for parts
• 4”x6”, 4mil antistatic for the MOSFET
• 4”x6”, 4mil antistatic for the other small parts
• 8”x10”, 6mil for holding everything

Other Supplies in ENS212
• 12Vdc regulated wall wart (marked with red paint), 2.1mm, Stancor STA-300R (Newark #84F2081 or #16M4578)
PWM Modulator (On Semiconductor MC34060A)

MOSFET Driver, Inverting and Non-Inverting, (MICROCHIP TC1426CPA and TC1427CPA, respectively)